

Pch -30V -10A Power MOSFET

V_{DSS}	-30V
$R_{DS(on)}(Max.)$	12.6m Ω
I _D	-10A
P_D	2.0W

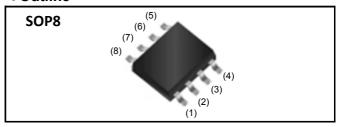
Features

- 1) Low on resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (SOP8).
- 4) Pb-free lead plating; RoHS compliant

Application

DC/DC Converter

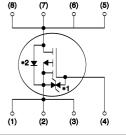
Outline



•Inner circuit

- (1) Source(2) Source
- (5) Drain
- (3) Source
- (6) Drain (7) Drain
- (4) Gate
- (8) Drain





Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Typo	Tape width (mm)	12
Туре	Basic ordering unit (pcs)	2,500
	Taping code	ТВ
	Marking	RRH100P03

●Absolute maximum ratings(T_a = 25°C)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	-30	V
Continuous drain current	I _D *1	±10	Α
Pulsed drain current	I _{D,pulse} *2	±40	Α
Gate - Source voltage	V_{GSS}	±20	V
Avalanche energy, single pulse	E _{AS} *3	0.8	mJ
Power dissipation	P _D *4	2.0	W
Power dissipation	P _D *5	0.65	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	−55 to +150	°C

●Thermal resistance

Parameter	Symbol	Values			Unit
- Farametei	Зуппоп	Min.	Тур.	Max.	Offic
Thermal resistance, junction - ambient	R _{thJA} *4	-	-	62.5	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	-	192	°C/W

•Electrical characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit	
r ai ai ii etei	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	V _{(BR)DSS}	V_{GS} = 0V, I_D = -1 mA	-30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I _D = -1mA referenced to 25°C	1	-25	-	mV/°C	
Zero gate voltage drain current	I _{DSS}	$V_{DS} = -30V, V_{GS} = 0V$	ı	-	-1	μА	
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	I	ı	±10	μΑ	
Gate threshold voltage	V _{GS (th)}	$V_{DS} = -10V, I_{D} = -1mA$	-1.0	ı	-2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{(GS)th}}{\Delta T_{j}}$	I _D = -1mA referenced to 25°C	-	3.9	-	mV/°C	
		V _{GS} = -10V, I _D = -10A	-	9.0	12.6		
Static drain - source	R _{DS(on)} *6	V_{GS} = -4.5V, I_{D} = -5A	-	12.5	17.5	mO	
on - state resistance		$V_{GS} = -4.0V, I_D = -5A$	-	14.0	19.6	mΩ	
		V _{GS} = -10V, I _D = -10A, T _j =125°C	ı	14.0	20.0		
Gate input resistannce	R_{G}	f = 1MHz, open drain	-	3.0	-	Ω	
Transconductance	9 fs *6	$V_{DS} = -10V, I_{D} = -10A$	13	26	-	S	

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 $\mu s,~Duty~cycle \leq$ 1%

^{*3} L \simeq 10 μ H, V_{DD} = -15V, Rg = 25 Ω , starting T_i = 25 $^{\circ}$ C

^{*4} Mounted on a ceramic board (30×30×0.8mm)

^{*5} Mounted on a FR4 (20×20×0.8mm)

•Electrical characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Syllibol	Symbol Conditions —		Тур.	Max.	Offic
Input capacitance	C _{iss}	V _{GS} = 0V	-	3600	-	
Output capacitance	C_{oss}	V _{DS} = -10V	-	450	-	pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	450	-	
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq -15V$, $V_{GS} = -10V$	1	25	-	
Rise time	t _r *6	$I_D = -5A$	-	60	-	no
Turn - off delay time	${\rm t_{d(off)}}^{*6}$	$R_L = 3.0\Omega$	-	150	-	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	100	-	

•Gate Charge characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	${\sf Q_g}^{*6}$	$V_{DD}^{\sim} -15V, I_{D} = -10A$ $V_{GS} = -5V$	-	39	-	
Total gate charge	\mathcal{Q}_{g}	$V_{DD} \simeq -15V, I_{D} = -10A$ $V_{GS} = -10V$	-	68	-	nC
Gate - Source charge	Q _{gs} *6	$V_{DD}^{\sim} -15V, I_{D} = -10A$ $V_{GS} = -5V$	1	8.5	-	
Gate - Drain charge	Q _{gd} *6	$V_{GS} = -5V$	-	13.5	-	

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol Conditions -		Values			Unit
- Faranietei	Syllibol	Symbol Conditions -		Тур.	Max.	Offic
Inverse diode continuous, forward current	l _S *1	T _a = 25°C	-	-	-1.6	А
Forward voltage	V _{SD} *6	$V_{GS} = 0V, I_{s} = -10A$	_	-	-1.2	V
Reverse recovery time	t _{rr} *6	I _S = -10A	ı	40	80	ns
Reverse recovery charge	Q _{rr} *6	di/dt = 100A / μs	ı	35	70	μС

^{*6} Pulsed

Fig.1 Power Dissipation Derating Curve

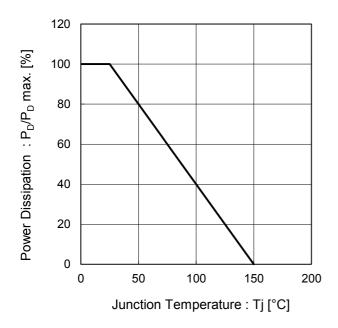


Fig.2 Maximum Safe Operating Area

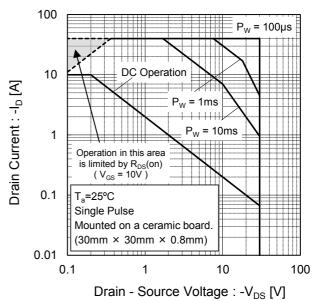
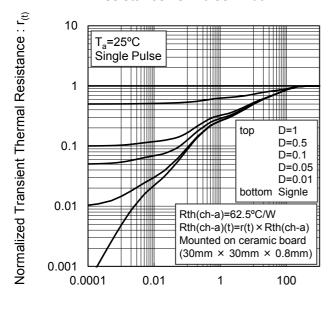
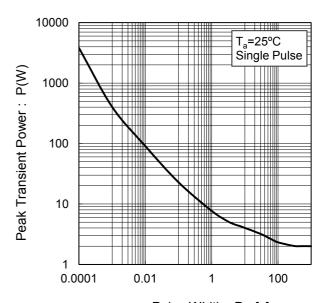


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width : P_W [s]

Fig.4 Single Pulse Maxmum Power dissipation



Pulse Width : P_W [s]

Fig.5 Avalanche Current vs Inductive Load

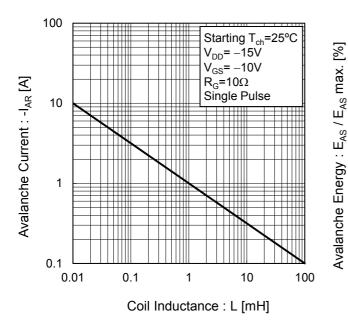


Fig.6 Avalanche Energy Derating Curve vs Junction Temperature

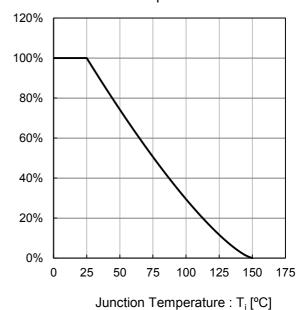


Fig.7 Typical Output Characteristics(I)

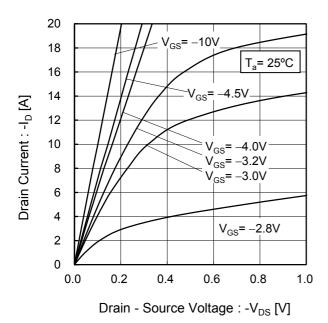
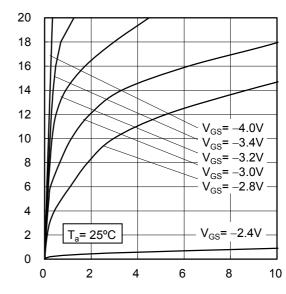


Fig.8 Typical Output Characteristics(II)



Drain Current: -l_D [A]

Fig.9 Breakdown Voltage
vs. Junction Temperature

VGB = 0V

VGB = 0V

ID = -1mA

40

Junction Temperature : T_i [°C]

Fig.10 Typical Transfer Characteristics

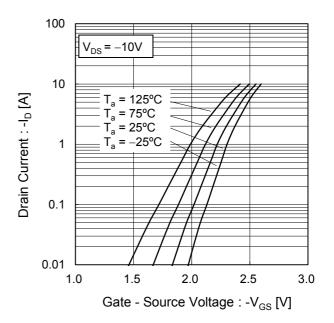


Fig.11 Gate Threshold Voltage vs. Junction Temperature

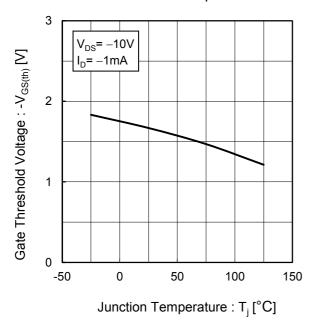


Fig.12 Transconductance vs. Drain Current

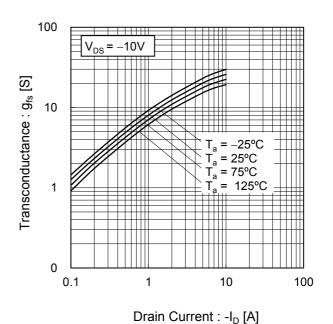


Fig.13 Drain CurrentDerating Curve

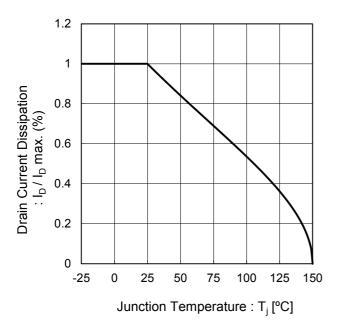
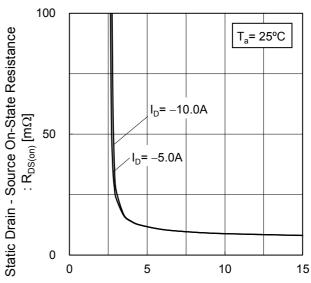


Fig.14 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Gate - Source Voltage : -V_{GS} [V]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(I)

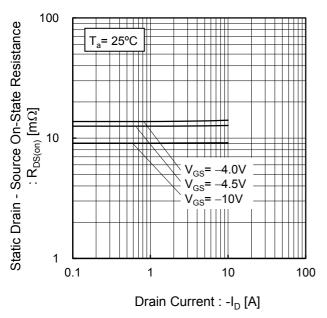
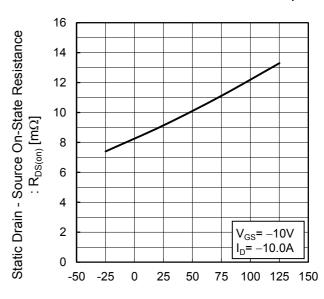


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature



Junction Temperature : T_i [°C]

= 125°C

10

100

•Electrical characteristic curves

Fig.17 Static Drain - Source On - State Fig.18 Static Drain - Source On - State Resistance vs. Drain Current(II) Resistance vs. Drain Current(III) 100 100 Static Drain - Source On-State Resistance Static Drain - Source On-State Resistance -10V $:R_{\mathsf{DS}(\mathsf{on})}\left[\mathsf{m}\Omega\right]$ $:R_{DS(on)}\left[m\Omega \right]$ 10 10 $T_a = 75^{\circ}C$ $T_a = 25^{\circ}C$ = 125°C = 75°C T_a = 25°C $T_a = -25$ °C = -25°C 1 0.1 10 0.1 1 1 100 Drain Current : -I_D [A] Drain Current : -I_D [A]

Resistance vs. Drain Current(IV) 100 Static Drain - Source On-State Resistance 4.0V $: R_{\mathsf{DS}(\mathsf{on})} \, [\mathsf{m} \Omega]$ 10 $T_a = 125^{\circ}C$ $T_a = 75^{\circ}C$ $T_a = 25^{\circ}C$ $T_a^{\circ} = -25^{\circ}C$ 0.1 10 100

Drain Current : -I_D [A]

Fig.19 Static Drain - Source On - State

Fig.20 Typical Capacitance vs. Drain - Source Voltage 10000 +++++ C_{iss} Capacitance : C [pF] 1000 $\mathsf{C}_{\mathsf{rss}}$ C_{oss} 100 T_a = 25°C f=1MHz $V_{GS}=0V$ 10 0.01 0.1 10 100 Drain - Source Voltage : -V_{DS} [V]

Fig.21 Switching Characteristics

Fig.22 Dynamic Input Characteristics

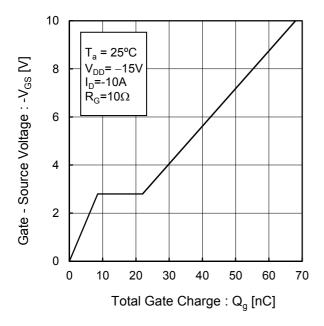
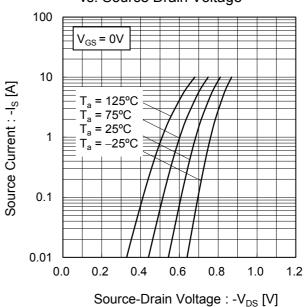


Fig.23 Source Current vs. Source Drain Voltage

Drain Current : -I_D [A]



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

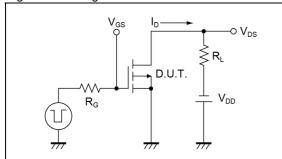


Fig.2-1 Gate Charge Measurement Circuit

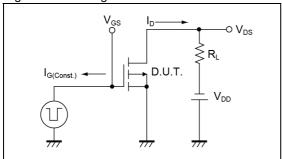


Fig.3-1 Avalanche Measurement Circuit

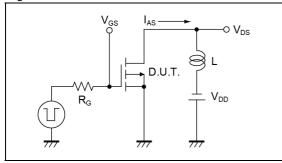


Fig.1-2 Switching Waveforms

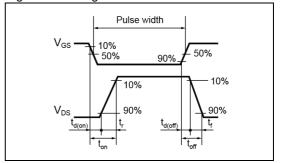


Fig.2-2 Gate Charge Waveform

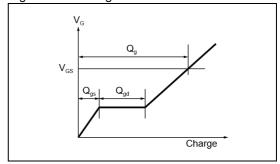
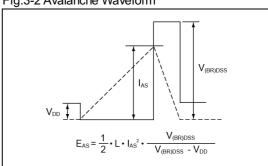
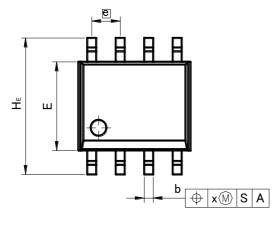


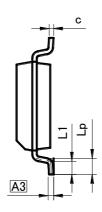
Fig.3-2 Avalanche Waveform

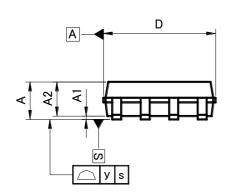


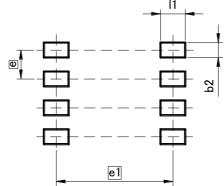
●Dimensions (Unit : mm)











Patterm of terminal position areas

DIM	MILIMI	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	1.75	_	0.069
A1	0.	15	0.0	006
A2	1.40	1.60	0.055	0.063
A3	0.2	25	0.0	01
b	0.30	0.50	0.012	0.02
С	0.10	0.30	0.004	0.012
D	4.80	5.20	0.189	0.205
Е	3.75	4.05	0.148	0.159
е	1.2	27	0.0	05
HE	5.70	6.30	0.224	0.248
L1	0.50	0.70	0.02	0.028
Lp	0.65	0.85	0.026	0.033
х	0.15		0.0	006
у	0.	10	0.0	004

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2	_	0.65	_	0.026
e1	5.	15	0.2	03
l1	_	1.15	_	0.045

Dimension in mm/inches

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CLASSⅢ	CL ACCIII	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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